

RoHS Compliant



Description:

MLCC consists of a conducting material and electrodes. To manufacture a chip-type SMT and achieve miniaturization, high density and high efficiency, ceramic condensers are used. The MLCC is made by NP0, X7R, X6S, X5R and Y5V dielectric material and which provides product with high electrical precision, stability and reliability.

Features:

- A wide selection of sizes is available (0201 to 1812).
- · High capacitance in given case size.
- · Capacitor with lead-free termination (pure Tin).

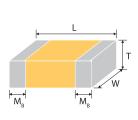
Applications:

- · For general digital circuit.
- · For power supply bypass capacitors.
- · For consumer electronics.
- · For telecommunication.

How To Order:

МС	1206	В	104	K	500	С	Т
IVIC	<u>Size</u>	Dielectric	<u>Capacitance</u>	<u>Tolerance</u>	Rated Voltage	<u>Termination</u>	Packaging style
Multicomp	Inch (mm) 0201 (0603) 0402 (1005) 0603 (1608) 0805 (2012) 1206 (3216) 1210 (3225) 1812 (4532)	N=NP0 (C0G) B=X7R F=Y5V X=X5R S=X6S	Two significant digits followed by no. of zeros. And R is in place of decimal point. Eg.: 0R5=0.5pF 1R0=1.0pF 104 = 10×10 ⁴ = 100nF	A=±0.05pF B=±0.1pF C=±0.25pF D=±0.5pF F=±1% G=±2% J=±5% K=±10% M=±20% Z=-20/+80%	Two significant digits followed by no. of zeros. And R is in place of decimal point. 4R0=4V DC 6R3=6.3V DC 100=10V DC 160=16V DC 250=25V DC 500=50V DC 101=100V DC	C=Cu/Ni/Sn	T=7" reeled R=7" reeled (2mm pitch for 0603 size; paper tape) G=13" reeled

External Dimensions:



The outline of MLCC

Size Inch (mm)	L (mm)	W (mm)	T (mm)/Symbo	ol	Soldering Method *	M _B (mm)
01R5 (0402)	0.4 ±0.02	0.2 ±0.02	0.2 ±0.02	V	R	0.1 ±0.03
0201	0.6±0.03	0.3 ±0.03	0.3 ±0.03			0.15 +0.05
(0603)	0.6±0.05 ^{#2}	0.3 ±0.05 ^{#2}	0.3 ±0.05 ^{#2}	L	R	0.15 ±0.05
(0000)	0.6±0.09 ^{#3}	0.3 ±0.09 ^{#3}	0.3 ±0.09 ^{#3}			0.15 +0.1/-0.05
	1 ±0.05	0.5 ±0.05	0.5 ±0.05	N		
0402 (1005)	1 ±0.05	0.5 ±0.05	0.5 +0.02/-0.05	Q	R	0.25 +0.05/-0.1
(1000)	1 ±0.2	0.5 ±0.2	0.5 ±0.2	Е		10.00/ 0.1





Size Inch (mm)	L (mm)	W (mm)	T (mm)/Symb	ol	Soldering Method *	M _B (mm)
	1.6 ±0.1	0.8 ±0.1	0.8 ±0.07	S	R/W	
0603	1.6 +0.15/-	0.8 +0.15/-0.1	0.5 ±0.1	Н	R/W	0.4 ±0.15
(1608)	0.1	0.6 +0.15/-0.1	0.8 +0.15/-0.1	X	R/W	0.4 ±0.15
	1.6 ±0.2* ¹	0.8 ±0.2* ¹	0.8 ±0.2* ¹	<u> </u>	K/W	
			0.5 ±0.1	Н	R/W	
	2 ±0.15	1.25 ±0.1	0.6 ±0.1	Α	R/W	
0805	2 ±0.13	1.25 ±0.1	0.8 ±0.1	В	R/W	0.5 ±0.2
(2012)			1.25 ±0.1	D	R	0.5 ±0.2
	2 ±0.2	1.25 ±0.2	0.85 ±0.1	Т	R/W	
	2 ±0.2	1.25 ±0.2	1.25 ±0.2	I	R	
			0.8 ±0.1	В	R/W	
	3.2 ±0.15	1.6 ±0.15	0.95 ±0.1	С	R	
		1.0 ±0.15	1.25 ±0.1	D	R	
1206 (3216)			1.15 ±0.15	J	R	0.6 ±0.2 (0.5±0.25)***
(0210)	3.2 ±0.2	16.02	1.6 ±0.2	G	R	(0.010.20)
		1.6 ±0.2	0.85 ±0.1	Т	R/W	
	3.2 +0.3/-0.1	1.6 +0.30/-0.1	1.6 +0.3/-0.1	Р	R	
			0.95 ±0.1	С	R	
	3.2 ±0.3	2.5±0.2	0.85 ±0.1	Т	R	
1210			1.25 ±0.1	D	R	0.75 ±0.25
(3225)			1.6 ±0.2	G	R	0.75 ±0.25
	3.2±0.4	2.5±0.3	2 ±0.2	K	R	
			2.5 ±0.3	М	R	
			1.25 ±0.1	D	R	
1808	4.5 ±0.4	2.03 ±0.25	1.4 ±0.15	F	R	0.75 ±0.25
(4520)	(4.5+0.5/- 0.3)**	2.03 ±0.25	1.6 ±0.2	G	R	(0.5±0.25)***
	213)		2 ±0.2	K	R	
			1.25 ±0.1	D	R	
40.10	4.5 ±0.4	3.2 ±0.3	1.6 ±0.2	G	R	0.75 0.05
1812 (4532)	4.5+0.5/-		2 ±0.2	K	R	0.75 ±0.25 0.5±0.25)***
(4002)	0.3)**	3.2 ±0.4	2.5 ±0.3	М	R	0.0±0.20)
		3.∠ ±0.4	2.8 ±0.3	U	R	

^{*} R = Reflow soldering process; W = Wave soldering process.



^{**} For 1808_200V ~3kV, 1812_200V~3kV and safety certificated products.

^{***} For 1206_1000V ~3kV, 1808_200V ~3kV, 1812_200V~3kV and safety certificated products.

^{#1:} For 0603/Cap \geq 10 μ F or 0603(>10V)/Cap>1 μ F products.

^{#2:} For 0201/Cap≥0.68µF products.

^{#3:} For 0201/Cap $>1\mu$ F products.



General Electrical Data:

Dielectric	NP0	X7R	Y5V	X5R	X6S
Size		0402, 060	3, 0805, 1206, 121	0, 1812	<u></u>
Capacitance range*	0.1pF to 0.1μF	100pF to 47μF	0.01μF to 100μF	100pF to 220μF	0.1μF to 100μF
Capacitance tolerance**	Cap≤5pF#1: A (±0.05pF), B (±0.1pF), C (±0.25pF) 5pF <cap<10pf: (±0.25pf),="" (±0.5pf)="" (±1%),="" (±10%)<="" (±2%),="" (±5%),="" c="" cap≥10pf:="" d="" f="" g="" j="" k="" th=""><th>J (±5%), K (±10%), M (±20%)</th><th>M (±20%), Z (-20/+80%)</th><th>K (±10%), M (±20%)</th><th>K (±10%), M (±20%)</th></cap<10pf:>	J (±5%), K (±10%), M (±20%)	M (±20%), Z (-20/+80%)	K (±10%), M (±20%)	K (±10%), M (±20%)
Rated voltage (WVDC)	10V, 16V, 25V, 50V,100V	6.3V, 10V, 16V,	25V, 50V, 100V	4V, 6.3V, 10V,	16V, 25V, 50V
DF(Tan δ)*	Cap<30pF: Q≥400+20C Cap≥30pF: Q≥1000		N	lote 1	
Operating temperature	-55 to +12	5°C	-25°C to +85°C	-55°C to +85°C	-55°C to +105°C
Capacitance characteristic	±30ppm	±15%	+30/-80%	±15%	±22%
Termination		Ni/Sn			

#1: NP0, 0.1pF product only provide B tolerance

NP0: Apply 1.0±0.2Vrms, 1.0MHz±10% for Cap≤1000pF and 1.0±0.2Vrms, 1.0kHz±10% for Cap>1000pF, 25°C at ambient temperature

X7R/X6S/X5R: Apply 1.0±0.2Vrms, 1.0kHz±10%, at 25°C ambient temperature.

Y5V: Apply 1.0±0.2Vrms, 1.0kHz±10%, at 20°C ambient temperature.

** Preconditioning for Class II MLCC: Perform a heat treatment at 150±10°C for 1 hour, then leave in ambient condition for 24±2 hours before measurement.



^{*} Measured at the condition of 30~70% related humidity.



Note 1:

X7R/X5R/X6S

Rated Vol.	D.F. ≦		Exception of D.F.≦
≧100V	≦2.5%	≦3%	1206≧0.47µF
= 100V	=2.5%	≦5%	0805>0.1μF, 0603≧0.068μF, 1206>1μF; TT series
		≦3%	0201(50V); 0603≧0.047μF; 0805≧0.18μF;1206≧0.47μF
50V	≦2.5%	≦5%	1210≧4.7µF
	-2.576	≦10%	0402 \ge 0.1 µF;0603 \ge 1 µF;0805 \ge 1 µF;1206 \ge 2.2 µF; 1210 \ge 10 µF;TT series
35V	≦3.5%	≦10%	0603≧1μF;0805≥2.2μF; 1210≧10μF
		≦5%	0201≥0.01μF;0805≥1μF;1210≥10μF
		≦7%	0603≧0.33μF; 1206≧4.7μF
25V	≦3.5%	≦10%	0402≧0.10μF;0603≧0.47μF; 0805≧2.2μF; 1206≧6.8μF ; 1210≧22μF ; TT series
		≦12.5%	0402≧1µF
16V	≦3.5%	≦5%	0201≥0.01µF;0402≥0.033µF; 0603≥0.15µF; 0805≥0.68µ 1206≥2.2µF;1210≥4.7µF
160	=3.5%	≦10%	0201≥0.1μF;0402≥ 0.22uF; 0603≥0.68μF;0805≥2.2μF; 1206≥4.7μF; 1210≥22μF; TT series
10V	≦5%	≦10%	0201 \ge 0.012µF;0402 \ge 0.33µF(0402/X7R \ge 0.22µF); TT series 0603 \ge 0.33µF; 0805 \ge 2.2µF;1206 \ge 2.2µF;1210 \ge 22µF
		≦15%	0201≧0.1μF; 0402≧1μF
6.3V	≦10%	≦15%	0201≥0.1μF;0402≥1μF;0603≥10μF; 0805≥4.7μF; 1206≥47μF:1210≥100μF; TT series
		≦20%	0402≧2.2μF
4V	≦15%		

Y5V

Rated vol.	D.F.≦		Exception of D.F.≦
≧50V	5%	7%	0603 ≥ 0.1μF; 0805 ≥ 0.47μF; 1206 ≥ 4.7μF
35V	7%		
25V	5%	7%	0402 \ge 0.047µF;0603 \ge 0.1µF; 0805 \ge 0.33µF;1206 \ge 1µF; 1210 \ge 4.7µF
20 0		9%	$0402 \ge 0.068 \mu F; 0603 \ge 0.47 \mu F; 1206 \ge 4.7 \mu F; 1210 \ge 22 \mu F$
16V (C<1.0µF)	7%	9%	0402≧0.068μF; 0603≧0.68μF
16ν (С<1.0με)	1 70	12.5%	0402≧0.22µF
16V (C≧1.0µF)	9%	12.5%	0603≥2.2μF; 0805≥3.3μF; 1206≥10μF; 1210≥22μF; 1812≥47μF
10V	12.5%	20%	0402≧0.47μF
6.3V	20%		



Capacitance Range

NP0 Dielectric 0201, 0402, 0603, 0805 Sizes

	Dielectric									NI	P0								
	Size		0201				0402					0603					0805		
F	Rated Voltage (V DC)	16	25	50	10	16	25	50	100	10	16	25	50	100	10	16	25	50	100
	0.1pF (0R1)	L	L	L	N	N	N	N											
	0.2pF (0R2)	L	L	L	N	N	N	N											
	0.3pF (0R3)	L	L	L	N	N	N	N											
	0.4pF (0R4)	L	L	L	N	N	N	N											
	0.5pF (0R5)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	А	Α	А	Α
	0.6pF (0R6)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	0.7pF (0R7)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	0.8pF (0R8)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	0.9pF (0R9)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	1.0pF (1R0)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	1.2pF (1R2)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	1.5pF (1R5)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	1.8pF (1R8)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	2.0pF (2R0)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	2.2pF (2R2)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	2.7pF (2R7)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	3.0pF (3R0)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
ė	3.3pF (3R3)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
Capacitance	3.9pF (3R9)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
acit	4.0pF (4R0)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
ар	4.7pF (4R7)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	А	Α	Α	Α
O	5.0pF (5R0)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	5.6pF (5R6)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	6.0pF (6R0)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	6.8pF (6R8)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	7.0pF (7R0)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	8.0pF (8R0)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	8.2pF (8R2)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	9.0pF (9R0)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	10pF (100)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	12pF (120)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	А	Α	А	Α
	15pF (150)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	А
	18pF (180)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	22pF (220)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	27pF (270)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	А	Α
	33pF (330)	L	L	L	N	N	N	N	N	S	S	S	S	S	А	А	Α	Α	Α
	39pF (390)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α
	47pF (470)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	А	Α	А	А
	56pF (560)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	Α	Α	Α	Α





	Dielectric	Π								NI	P0								
	Size		0201				0402					0603					0805		
F	Rated Voltage (V DC)	16	25	50	10	16	25	50	100	10	16	25	50	100	10	16	25	50	100
	68pF (680)	L	L	L	N	N	N	N	N	S	S	S	S	S	А	А	Α	А	Α
	82pF (820)	L	L	L	N	N	N	N	N	S	S	s	S	S	Α	А	А	А	Α
	100pF (101)	L	L	L	N	N	N	N	N	S	S	S	S	S	Α	А	А	А	Α
	120pF (121)	L	L	L	N	N	N	N	N	S	S	s	S	s	Α	Α	Α	А	Α
	150pF (151)				N	N	N	N	N	S	S	S	S	S	Α	А	А	А	Α
	180pF (181)				N	N	N	N	N	S	S	S	S	S	Α	А	А	А	А
	220pF (221)				N	N	N	N	N	S	S	S	S	S	Α	А	А	А	Α
	270pF (271)				N	N	N	N		S	S	S	S	S	Α	А	Α	А	Α
	330pF (331)				N	N	N	N		S	S	S	S	S	Α	А	Α	А	Α
	390pF (391)				N	N	N	N		S	S	S	S	S	В	В	В	В	В
	470pF (471)				N	N	N	N		S	S	S	S	S	В	В	В	В	В
	560pF (561)				N	N	N	N		S	S	S	S	S	В	В	В	В	В
	680pF (681)				N	N	N	N		S	S	S	S	S	В	В	В	В	В
) ce	820pF (821)				N	N	N	N		S	S	S	S	S	В	В	В	В	В
itar	1,000pF (102)				N	N	N	N		S	S	S	S	S	В	В	В	В	В
Capacitance	1,200pF (122)									Х	Х	Х	Х	Х	В	В	В	В	В
Car	1,500pF (152)									Х	Х	Х	Х	Х	В	В	В	В	В
	1,800pF (182)									Х	Х	Х	Х		В	В	В	В	В
	2,200pF (222)									Х	Х	Х	Х		В	В	В	В	В
	2,700pF (272)									Х	Х	Х	Х		D	D	D	D	D
	3,300pF (332)									Х	Х	Х	Х		D	D	D	D	D
	3,900pF (392)									Х	Х	Х	Х		D	D	D	D	D
	4,700pF (472)									Х	Х	Х	Х		D	D	D	D	D
	5,600pF (562)									Х	Х	Х	Х		D	D	D	D	D
	6,800pF (682)									Х	Х	Х	Х		D	D	D	D	D
	8,200pF (822)									Х	Х	Х	Х		D	D	D	D	
	0.010uF (103)									Х	Х	Х	Х		D	D	D	D	
	0.012uF (123)														Т	Т	Т	Т	
	0.018uF (183)														D	D	D	D	
	0.022uF (223)														D	D	D	D	

^{1.} The letter in cell is expressed the symbol of product thickness.

NP0 Dielectric 1206, 1210, 1812 Sizes

	Dielectric							NP0						
	Size			1206					1210				1812	
F	Rated Voltage (V DC)		16	25	50	100	10	16	25	50	100	16	50	100
ø	1.0pF (1R0)													
anc	1.2pF (1R2) 1.5pF (1R5) 1.8pF (1R8)		В	В	В	В								
cit	1.5pF (1R5)		В	В	В	В								
ара	1.8pF (1R8)	В	В	В	В	В								
ပိ	2.2pF (2R2)	В	В	В	В	В								





	Dielectric							NP0						
	Size			1206					1210				1812	
F	Rated Voltage (V DC)	10	16	25	50	100	10	16	25	50	100	16	50	100
	2.7pF (2R7)	В	В	В	В	В								
	3.3pF (3R3)	В	В	В	В	В								
	3.9pF (3R9)	В	В	В	В	В								
	4.7pF (4R7)	В	В	В	В	В								
	5.6pF (5R6)	В	В	В	В	В								
	6.8pF (6R8)	В	В	В	В	В								
	8.2pF (8R2)	В	В	В	В	В								
	10pF (100)	В	В	В	В	В	С	С	С	С	С	D	D	D
	12pF (120)	В	В	В	В	В	С	С	С	С	С	D	D	D
	15pF (150)	В	В	В	В	В	С	С	С	С	С	D	D	D
	18pF (180)	В	В	В	В	В	С	С	С	С	С	D	D	D
	22pF (220)	В	В	В	В	В	С	С	С	С	С	D	D	D
	27pF (270)	В	В	В	В	В	С	С	С	С	С	D	D	D
	33pF (330)	В	В	В	В	В	С	С	С	С	С	D	D	D
	39pF (390)	В	В	В	В	В	С	С	С	С	С	D	D	D
	47pF (470)	В	В	В	В	В	С	С	С	С	С	D	D	D
	56pF (560)	В	В	В	В	В	С	С	С	С	С	D	D	D
	68pF (680)	В	В	В	В	В	С	С	С	С	С	D	D	D
	82pF (820)	В	В	В	В	В	С	С	С	С	С	D	D	D
8	100pF (101)	В	В	В	В	В	С	С	С	С	С	D	D	D
itan	120pF (121)	В	В	В	В	В	С	С	С	С	С	D	D	D
Capacitance	150pF (151)	В	В	В	В	В	С	С	С	С	С	D	D	D
ပိ	180pF (181)	В	В	В	В	В	С	С	С	С	С	D	D	D
	220pF (221)	В	В	В	В	В	С	С	С	С	С	D	D	D
	270pF (271)	В	В	В	В	В	С	С	С	С	С	D	D	D
	330pF (331)	В	В	В	В	В	С	С	С	С	С	D	D	D
	390pF (391)	В	В	В	В	В	С	С	С	С	С	D	D	D
	470pF (471)	В	В	В	В	В	С	С	С	С	С	D	D	D
	560pF (561)	В	В	В	В	В	С	С	С	С	С	D	D	D
	680pF (681)	В	В	В	В	В	С	С	С	С	С	D	D	D
	820pF (821)	В	В	В	В	В	С	С	С	С	С	D	D	D
	1,000pF (102)	В	В	В	В	В	С	С	С	С	С	D	D	D
	1,200pF (122)	В	В	В	В	В	С	С	С	С	С	D	D	D
	1,500pF (152)	В	В	В	В	В	С	С	С	С	С	D	D	D
	1,800pF (182)	В	В	В	В	В	С	С	С	С	С	D	D	D
	2,200pF (222)	В	В	В	В	В	С	С	С	С	С	D	D	D
	2,700pF (272)	В	В	В	В	В	С	С	С	С	С	D	D	D
	3,300pF (332)	В	В	В	В	В	С	С	С	С	С	D	D	D
	3,900pF (392)	В	В	В	В	В	С	С	С	С	С	D	D	D
	4,700pF (472)	В	В	В	В	В	С	С	С	С	С	D	D	D
	5,600pF (562)	В	В	В	В	В	С	С	С	С	С	D	D	D
	6,800pF (682)	С	С	С	С	С	С	С	С	С	С	D	D	D





	Dielectric							NP0						
	Size			1206					1210				1812	
F	Rated Voltage (V DC)	10	16	25	50	100	10	16	25	50	100	16	50	100
	8,200pF (822)	D	D	D	D	D	С	С	С	С	С	D	D	D
	0.010µF (103)	D	D	D	D	D	С	С	С	С	С	D	D	D
	0.012μF (123)	Т	Т	Т	Т	Т	D	D	D	D	D	D	D	D
	0.015µF (153)	Т	Т	Т	Т	Т	D	D	D	D	D	D	D	D
	0.018µF (183)	Т	Т	Т	Т	Т						D	D	D
ඉ	0.022µF (223)	Т	Т	Т	Т	Т						D	D	D
itan	0.022µF (223) 0.027µF (273) 0.033µF (333) 0.020µF (203)		Т	Т	Т							D	D	D
pac	0.033µF (333)	Т	Т	Т	Т							D	D	D
ပြိ	0.039µF (393)	J	J	J	J									
	0.047µF (473)	J	J	J	J									
	0.056µF (563)	J	J	J	J									
	0.068µF (683)	G	G	G	G									
	0.082µF (823)	G	G	G	G									
	0.1μF (104)	G	G	G	G									

^{1.} The letter in cell is expressed the symbol of product thickness.

X7R Dielectric 0201, 0402, 0603, 0805 Sizes

	Dielectric		X7R 0201 0402 0603 0805																					
	Size			0201					04	02					06	03					08	05		
Ra	ated Voltage (V DC)	6.3	10	16	25	50	6.3	10	16	25	50	100	6.3	10	16	25	50	100	6.3	10	16	25	50	100
	100pF (101)			L	L	L		N	N	N	N	N		S	s	S	S	s		В	В	В	В	В
	120pF (121)			L	L	L		N	N	N	N	N		S	S	S	S	s		В	В	В	В	В
	150pF (151)			L	L	L		N	N	N	N	N		S	S	S	S	S		В	В	В	В	В
	180pF (181)			L	L	L		N	N	N	N	N		S	S	S	S	S		В	В	В	В	В
	220pF (221)			L	L	L		N	N	N	N	N		S	s	S	S	s		В	В	В	В	В
	270pF (271)			L	L	L		N	N	N	N	N		S	s	S	S	S		В	В	В	В	В
	330pF (331)			L	L	L		N	N	N	N	N		S	s	S	S	s		В	В	В	В	В
	390pF (391)			L	L	L		N	N	N	N	N		S	s	S	S	s		В	В	В	В	В
ස	470pF (471)			L	L	L		N	N	N	N	N		S	S	S	S	S		В	В	В	В	В
itan	560pF (561)			L	L	L		N	N	N	N	N		S	S	S	S	S		В	В	В	В	В
Capacitance	680pF (681)			L	L	L		N	N	N	N	N		S	S	S	S	S		В	В	В	В	В
ပိ	820pF (821)			L	L	L		N	N	N	N	N		S	S	S	S	S		В	В	В	В	В
	1,000pF (102)	L	L	L	L	L		N	N	N	N	N		S	S	S	S	S		В	В	В	В	В
	1,200pF (122)	L	L	L	L			N	N	N	N			S	S	S	S	s		В	В	В	В	В
	1,500pF (152)	L	L	L	L			N	N	N	N			S	S	S	S	s		В	В	В	В	В
	1,800pF (182)	L	L	L				N	N	N	N			S	S	S	S	S		В	В	В	В	В
	2,200pF (222)	L	L	L				N	N	N	N			S	S	S	S	S		В	В	В	В	В
	2,700pF (272)	L	L	L				N	N	N	N			S	S	S	S	S		В	В	В	В	В
	3,300pF (332)	L	L	L				N	N	N	N			S	S	S	S	s		В	В	В	В	В
	3,900pF (392)	L	L	L				N	N	N	N			S	s	S	S	S		В	В	В	В	В





	Dielectric												X7F	₹										
	Size			0201					04	02					06	03					08	05		
Ra	ted Voltage (V DC)	6.3	10	16	25	50	6.3	10	16	25	50	100	6.3	10	16	25	50	100	6.3	10	16	25	50	100
	4,700pF (472)	L	L	L				N	N	N	N			S	S	S	S	S		В	В	В	В	В
	5,600pF (562)	L	L					N	N	N	N			S	S	S	S	S		В	В	В	В	В
	6,800pF (682)	L	L					N	N	N	N			S	S	S	S	S		В	В	В	В	В
	8,200pF (822)	L	L					N	N	N	N			S	S	S	S	S		В	В	В	В	В
	0.010µF (103)	L	L	L				N	N	N	N			S	S	S	S	S		В	В	В	В	В
	0.012µF (123)							N	N	N				S	s	S	S	Х		В	В	В	В	В
	0.015µF (153)							N	N	N				S	s	S	S	Х		В	В	В	В	В
	0.018µF (183)							N	N	N				S	S	S	S	Х		В	В	В	В	В
	0.022µF (223)							N	N	N	N			S	S	S	S	Х		В	В	В	В	В
	0.027µF (273)							N	N	N				S	S	S	S	Х		В	В	В	В	D
	0.033µF (333)							N	N	N	N			S	s	S	Х	Х		В	В	В	В	D
	0.039µF (393)							N	N	N				S	s	S	Х	Х		В	В	В	В	D
	0.047µF (473)							N	N	N	N			S	S	S	Х	Х		В	В	В	В	D
	0.056µF (563)							N	N					S	S	S	Х	Х		В	В	В	В	D
	0.068µF (683)							N	N		N			S	S	S	Х	Х		В	В	В	В	D
	0.082µF (823)							N	N					S	S	S	Х	Х		В	В	В	В	D
_ გ	0.10µF (104)						N	N	N	N	N			S	S	S	Х	Х		В	В	В	В	D
itan	0.12µF (124)													S	S	Х				В	В	В	D	
Capacitance	0.15µF (154)													S	S	Х				D	D	D	D	
င္မ	0.18µF (184)													S	S	Х				D	D	D	D	
	0.22µF (224)						N	N	N	N				S	S	Х	Х			D	D	D	D	Т
	0.27µF (274)												Х	Х	Х	Х				D	D	D	ı	
	0.33µF (334)												Х	Х	Х	Х				D	D	D	ı	
	0.39µF (394)												Х	Х	Х	Х				D	D	D	ı	
	0.47µF (474)						N	N					Х	Х	Х	Х	Х			D	D	D	ı	1
	0.56µF (564)												Х	Х	Х					D	D	D		
	0.68µF (684)												Х	Х	Х					D	D	D		
	0.82µF (824)												Х	Х	Х					D	D	D		
	1.0µF (105)						N						Х	Х	Х	Х	Х			D	D	D	ı	
	1.5µF (155)																			I	ı	ı		
	2.2µF (225)												Х	Х					I	I	ı	ı	ı	
	3.3µF (335)																							
	4.7µF (475)																		ı	ı	ı	ı		
	6.8µF (685)																					Ì		
	10μF (106)																		ı	ı	l*			
	22µF (226)																							

- 1. The letter in cell is expressed the symbol of product thickness.
- 2. The letter in cell with " * " mark is expressed product not in 10% (code "K") tolerance.







X7R Dielectric 1206, 1210, 1812 Sizes

	Dielectric									X7R								
	Size			12	06					12	10					1812		
Ra	ited Voltage (V DC)	6.3	10	16	25	50	100	6.3	10	16	25	50	100	10	16	25	50	100
	100pF (101)																	
	120pF (121)																	
	150pF (151)		В	В	В	В	В											
	180pF (181)		В	В	В	В	В											
	220pF (221)		В	В	В	В	В											
	270pF (271)		В	В	В	В	В											
	330pF (331)		В	В	В	В	В											
	390pF (391)		В	В	В	В	В											
	470pF (471)		В	В	В	В	В											
	560pF (561)		В	В	В	В	В											
	680pF (681)		В	В	В	В	В											
	820pF (821)		В	В	В	В	В											
	1,000pF (102)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	1,200pF (122)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	1,500pF (152)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	1,800pF (182)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	2,200pF (222)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	2,700pF (272)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
Capacitance	3,300pF (332)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
acit	3,900pF (392)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
Сар	4,700pF (472)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	5,600pF (562)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	6,800pF (682)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	8,200pF (822)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.010µF (103)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.012µF (123)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.015µF (153)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.018µF (183)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.022µF (223)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.027µF (273)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.033µF (333)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.039µF (393)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.047µF (473)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.056µF (563)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.068µF (683)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.082µF (823)		В	В	В	В	D		С	С	С	С	С	D	D	D	D	D
	0.10µF (104)		В	В	В	В	D		С	С	С	С	С	D	D	D	D	D
	0.12µF (124)		В	В	В	В	D		С	С	С	С	С	D	D	D	D	D
	0.15µF (154)		С	С	С	С	G		С	С	С	С	D	D	D	D	D	D





I	Dielectric									X7R								
	Size			12	:06					12	10					1812		
Ra	ited Voltage (V DC)	6.3	10	16	25	50	100	6.3	10	16	25	50	100	10	16	25	50	100
	0.18µF (184)		С	С	С	С	G		С	С	С	С	D	D	D	D	D	D
	0.22µF (224)		С	С	С	С	G		С	С	С	С	D	D	D	D	D	D
	0.27µF (274)		С	С	С	D	G		С	С	С	С	G	D	D	D	D	D
	0.33µF (334)		С	С	С	D	G		С	С	С	D	G	D	D	D	D	D
	0.39µF (394)		С	С	J	Р	G		С	С	С	D	М	D	D	D	D	D
	0.47µF (474)		J	J	J	Р	G		С	С	С	D	М	D	D	D	D	К
	0.56µF (564)		J	J	J	Р	Р		D	D	D	D	М	D	D	D	D	К
_	0.68µF (684)		J	J	J	Р	Р		D	D	D	D	K	D	D	D	К	К
Capacitance	0.82µF (824)		J	J	J	Р	Р		D	D	D	D	K	D	D	D	К	К
acita	1.0µF (105)		J	J	J	Р	Р		D	D	D	D	K	D	D	D	К	К
Сар	1.5µF (155)	J	J	J	Р					K	G	М	М					К
	2.2µF (225)	J	J	J	Р	Р	Р			K	G	М	М				М	М
	3.3µF (335)		Р	Р	Р					K	G							
	4.7µF (475)	Р	Р	Р	Р	Р			K	K	K	М						
	6.8µF (685)																	
	10µF (106)	Р	Р	Р	Р				К	K	K	М						
	22µF (226)	Р	Р	P*					М	М	М							
	47µF (476)							М	М									
ı	100µF (107)																	

^{1.} The letter in cell is expressed the symbol of product thickness.

Y5V Dielectric 0402, 0603, 0805 Sizes

	Dielectric							•	Y	5V							
	Size			0402					0603					08	05		
Ra	ited Voltage (V DC)	6.3	10	16	25	50	6.3	10	16	25	50	6.3	10	16	25	50	100
	0.010µF (103)		N	N	N	N		S	S	S	S		Α	Α	Α	Α	В
	0.015µF (153)		N	N	N	N		S	S	S	S		Α	Α	Α	Α	В
	0.022µF (223)		N	N	N	N		S	S	S	S		Α	Α	Α	Α	В
	0.033µF (333)		N	N	N	N		S	S	S	S		Α	Α	Α	Α	В
	0.047µF (473)		N	N	N			S	S	S	S		Α	Α	Α	Α	В
ඉ	0.068µF (683)		N	N	N			S	S	S	S		Α	Α	Α	Α	В
Capacitance	0.10µF (104)		N	N	N			S	S	S	S		Α	Α	Α	Α	В
pac	0.15µF (154)		N	N				S	S	S	S		Α	Α	Α	Α	
ပိ	0.22µF (224)	N	N	N				S	S	S	S		Α	Α	Α	Α	
	0.33µF (334)	N	N	N				S	S	s	Х		В	В	В	В	
	0.47µF (474)	N	N	N				S	S	Х	Х		В	В	В	В	
	0.68µF (684)	N						S	Х	Х			В	В	D	D	
	1.0µF (105)	N	N					S	Х	Х			В	В	D	D	
	1.5µF (155)							S					D	D			



^{2.} The letter in cell with " * " mark is expressed product not in 10% (code "K") tolerance.



	Dielectric								Y!	5V							
	Size			0402					0603					08	05		
Ra	ited Voltage (V DC)	6.3	10	16	25	50	6.3	10	16	25	50	6.3	10	16	25	50	100
	2.2µF (225)						S	S	Х				D	D	I		
ළ	3.3µF (335)												D	D			
Capacitance	4.7μF (475)						Х	Х					D	D	I		
pac	6.8µF (685)												ı				
ပြီ	10μF (106)											ı	ı	ı			
	22µF (226)											Ī	Ī				

^{1.} The letter in cell is expressed the symbol of product thickness.

Y5V Dielectric 1206, 1210, 1812 Sizes

	Dielectric									Y5V								
	Size			12	06					1:	210					1812		
Ra	ted Voltage (V DC)	6.3	10	16	25	50	100	6.3	10	16	25	50	100	10	16	25	50	100
	0.010µF (103)		В	В	В	В	В						С					D
	0.015µF (153)		В	В	В	В	В						С					D
	0.022µF (223)		В	В	В	В	В						С					D
	0.033µF (333)		В	В	В	В	В						С					D
	0.047µF (473)		В	В	В	В	В						С					D
	0.068µF (683)		В	В	В	В	В						С					D
	0.10µF (104)		В	В	В	В	В		С	С	С	С	С	D	D	D	D	D
	0.15µF (154)		В	В	В	В	С		С	С	С	С	С	D	D	D	D	D
	0.22µF (224)		В	В	В	В	С		С	С	С	С	С	D	D	D	D	D
9	0.33µF (334)		В	В	В	В			С	С	С	С	С	D	D	D	D	D
itan	0.47µF (474)		В	В	В	В			С	С	С	С		D	D	D	D	D
Capacitance	0.68µF (684)		В	В	В	В			С	С	С	С		D	D	D	D	D
ြိ	1.0µF (105)		С	С	С	С			С	С	С	С		D	D	D	D	D
	1.5µF (155)		С	С	С				С	С	С			D	D	D	D	
	2.2µF (225)		С	С	С	J			С	С	С	G		D	D	D	D	
	3.3µF (335)		J	J	J				С	С	С			D	D	D	D	
	4.7µF (475)		J	J	J	Р			С	С	D	G		D	D	D	D	
	6.8µF (685)		J	J					С	С	D			D	D	D	D	
	10μF (106)		J	J	Р				D	D	G			D	D	D	К	
	22µF (226)		Р	Р					К	K								
	47µF (476)	Р						K	К						М			
	100μF (107)							М										

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^{1.} The letter in cell is expressed the symbol of product thickness.



X5R Dielectric 0201, 0402, 0603, 0805, 1206, 1210 Sizes

	Dielectric								X5R							
	Size			0201					0402					0603		
Rated	Voltage (V DC)	6.3	10	16	25	50	6.3	10	16	25	50	6.3	10	16	25	50
	100pF (101)			L	L	L										
	120pF (121)			L	L	L										
	150pF (151)			L	L	L										
	180pF (181)			L	L	L										
	220pF (221)			L	L	L										
	270pF (271)			L	L	L										
	330pF (331)			L	L	L										
	390pF (391)			L	L	L										
	470pF (471)			L	L	L										
	560pF (561)			L	L	L										
	680pF (681)			L	L	L										
	820pF (821)			L	L	L										
	1,000pF (102)		L	L	L	L										
	1,500pF (152)		L	L												
	2,200pF (222)		L	L												
	2,700pF (272)		L	L												Г
	3,300pF (332)		L	L												
	4,700pF (472)		L	L												
	6,800pF (682)		L													
8	0.010µF (103)	L	L	L	L											
Capacitance	0.015µF (153)	L	L													
paci	0.022µF (223)	L	L													
ပ္မ	0.027µF (273)	L	L						N							
	0.033µF (333)	L	L						N						İ	
	0.039µF (393)	L	L						N							
	0.047µF (473)	L	L						N							
	0.056µF (563)	L	L					N	N							
	0.068µF (683)	L	L					N	N							
	0.082µF (823)	L	L				N	N	N							İ
	0.10µF (104)	L	L	L	L		N	N	N	N	N					İ
	0.15µF (154)						N	N	N	N						İ
	0.22µF (224)	L	L				N	N	N	N	N			Х	Х	
	0.27uF (274)												Х	Х	Х	
	0.33µF (334)						N	N				Х	Х	Х	Х	
	0.39µF (394)												Х	Х	Х	İ
	0.47µF (474)	L					N	N	Е	Е	Е	Х	Х	Х	Х	X
	0.68µF (684)						N	N				Х	Х	Х	Х	Г
	0.82uF (824)											Х	Х	Х		Г
	1.0µF (105)	L	L*				N	N	N	N		Х	Х	Х		X
	1.5µF (155)											Х				
	2.2µF (225)	L*					N	N	E*	Е		Х	Х	Х	Х	X
	3.3µF (335)		İ									Х	Х		İ	İ





ı	Dielectric								X5R							
	Size			0201					0402					0603		
Rated	Voltage (V DC)	6.3	10	16	25	50	6.3	10	16	25	50	6.3	10	16	25	50
9	4.7µF (475)						E*	E*				Х	Х	Х	Х	
Capacitance	6.8uF (685)															
pac	10μF (106)						E*	E*				Х	Х	Х	X*	
ပိ	22µF (226)											X*	X*			

	Dielectric									X5R								
	Size			12	06					1210					18	12		
Rate	d Voltage (V DC)	4	6.3	10	16	25	50	6.3	10	16	25	50	4	6.3	10	16	25	50
	1.0µF (105)			D	D	D	I											
	1.5µF (155)		ı	I	ı	I			J	J					K	К		
	2.2µF (225)		1	ı	1	ı	ı		J	J	Р	Р			K	К		
	3.3µF (335)		ı	ı	ı	ı			Р	Р	Р							
Capacitance	4.7µF (475)		ı	ı	ı	ī	ı	Р	Р	Р	Р	Р			К	К	К	
acite	6.8uF (685)							Р	Р									
Cap	10μF (106)		ı	ı	ı	ı	ı	Р	Р	Р	Р	Р		K	K	К	К	М
	22µF (226)		l*	l*	l*			Р	Р	Р	Р			М	М	М	М	
	47µF (476)		l*	l*				Р	Р					М	М	М		
	100µF (107)	l*						P*						M*	М*			
	220µF (227)												М*					

^{1.} The letter in cell is expressed the symbol of product thickness.

X6S Dielectric 0201, 0402, 0603, 0805, 1206, 1210 Sizes

	Dielectric														X6S													
	Size	02	201		04	02				0603					08	05					1206					1210		
Rate	ed Voltage (V DC)	4	6.3	6.3	10	16	25	4	6.3	10	16	25	4	6.3	10	16	25	50	6.3	10	16	25	50	6.3	10	16	25	50
	0.10µF (104)	L	L																									
	0.15µF (154)																											
	0.22µF (224)		L																									
	0.33µF (334)																		ĺ									
	0.47µF (474)			N																								
	0.68µF (684)																											
ا بو	1.0µF (105)	L*		N	Е	Е	Е																					
Capacitance	1.5µF (155)																											
pac	2.2µF (225)			N	Е	Е						Х																
ပြိ	3.3µF (335)																											
	4.7µF (475)								Х		Х	Х					1	1										
	6.8uF (685)																											
	10μF (106)								X*	X*	X*		1	ı	ı	ı	ı					G						
	22µF (226)							X*	X*					l*	l*	l*				Р	P*						М	
	47μF (476)												l*						Р					М	М	М		
	100µF (107)											Ì				Ì			ĺ				Ì	M*				

^{1.} The letter in cell is expressed the symbol of product thickness.



^{2.} The letter in cell with " * " mark is expressed product not in 10% (code "K") tolerance.

^{2.} The letter in cell with " * " mark is expressed product not in 10% (code "K") tolerance.



Packaging Dimension And Quantity:

Size	Thickness (mm)/S	tymbol	Pape	r tape	Plasti	c tape
Size	THICKHESS (IIIII)/S	yiiiboi	7" reel	13" reel	7" reel	13" reel
	0.3 ±0.03	L	15,000	70,000	-	-
0201 (0603)	0.3 ± 0.05	L	15,000	-	-	-
	0.3 ±0.09	L	15,000	-	-	-
	0.5 ±0.05	N	10,000	50,000	-	-
0402 (1005)	0.5 +0.02/-0.05	Q	10,000	50,000	-	-
	0.5 ±0.2	E	10,000	-	-	-
	0.5 ±0.1	Н	4,000	-	-	-
0603 (1608)	0.8 ±0.07	S	4,000	15,000	-	-
	0.8 +0.15/-0.1	Х	4,000	15,000	-	-
	0.5 ±0.1	Н	4,000	15,000	-	-
ĺ	0.6 ±0.1	А	4,000	15,000	-	-
0005 (2042)	0.8 ±0.1	В	4,000	15,000	-	-
0805 (2012)	0.85 ±0.1	Т	4,000	15,000	-	-
Ī	1.25 ±0.1	D	-	-	3,000	10,000
	1.25 ±0.2	ı	-	-	3,000	10,000
	0.8 ±0.1	В	4,000	15,000	-	-
	0.85 ±0.1	Т	4,000	15,000	-	-
	0.95 ±0.1	С	-	-	3,000	10,000
1206 (3216)	1.15 ±0.15	J	-	-	3,000	10,000
	1.25 ±0.1	D	-	-	3,000	10,000
	1.6 ±0.2	G	-	-	2,000	10,000
	1.6 +0.30/-0.10	Р	-	-	2,000	9,000
	0.85 ±0.1	Т	-	-	3,000	10,000
	0.95 ±0.1	С	-	-	3,000	10,000
4040 (0005)	1.25 ±0.1	D	-	-	3,000	10,000
1210 (3225)	1.6 ±0.2	G	-	-	2,000	-
Ī	2 ±0.2	К	-	-	1,000	6,000
Ī	2.5 ±0.3	М	-	-	1,000	6,000
	1.25 ±0.1	D	-	-	2,000	10,000
4000 (4500)	1.1 ±0.15	F	-	-	2,000	10,000
1808 (4520)	1.6 ±0.2	G	-	-	2,000	8,000
	2 ±0.2	К	-	-	1,000	6,000
	1.25 ±0.1	D	<u>-</u>	-	1,000	5,000
İ	1.6 ±0.2	G	-	-	1,000	-
1812 (4532)	2 ±0.2	К	-	-	1,000	-
Ī	2.5 ±0.3	М	-	-	500	3,000
Ī	2.8 ±0.3	U	-	-	500	-

Unit: pieces

Reliability Test Conditions And Requirements:

No	Item	Test Condition	Requirements
1	Visual and Mechanical	-	No remarkable defect. Dimensions to conForm to individual specification sheet.





No	Item	Test Condition				R	equirements	
2	Capacitance		*Shall n	ot exc	ceed	the lim	its given in the detailed spec.	
			NP0: Ca X7R,X5F			±1000; C	ap<30pF,Q≥400+20C	
			Rated vol.	D.F.≦	≦		Exception of D.F. ≦	
					П	≦3%	1206≧0.47µF	
			≧100V	≦2.5	5%	≦5%	0805>0.1μF, 0603≧0.068μF, 1206>1μF; TT series	
						≦3%	0201(50V); 0603≧0.047μF; 0805≧0.18μF;1206≧0.47μF	
			≧50V	≦2.5	5%	≦5%	1210≧4.7µF	
						≦10%	0402≧0.1μF; 0603≧1μF; 0805≧1μF; 1206≧4.7μF; 1210≧10μF TT series	
			35V	≦3.5	5%	≦10%	0603≧1μF; 0805≥2.2μF; 1210≧10μF	
					L	≦5%	0201 \ge 0.01 μ F;0805 \ge 1 μ F; 1210 \ge 10 μ F	
		Class I: NP0				≦7%	0603≧0.33μF; 1206≧4.7μF	
		Cap≤1000pF 1.0±0.2Vrms, 1MHz±10% Cap>1000pF 1.0±0.2Vrms, 1KHz±10% Class II: X7R, X5R, X6S,Y5V	25V	≦3.5		≦10%	0402 \ge 0.10µF;0603 \ge 0.47µF;0805 \ge 2.2 µF; 1206 \ge 6.8µF ; 1210 \ge 22µF; TT series	
		Cap≤10µF, 1.0±0.2Vrms, 1kHz±10% **		<u> </u>	≦	≦12.5%	0402≧1µF	
		Cap>10μF, 0.5±0.2Vrms, 120Hz±20% ** Test condition: 0.5±0.2Vrms, 1KHz±10% X7R: 0603≧225(10V), 0805=106(6.3V&10V)				≦5%	0201≧0.01μF; 0402≧0.033μF; 0805≧0.68μF;1206≧2.2μF;1210≧4.7μF	
	Q/ D.F.		16V	≦3.5°	- 1	≦10%	0201 \geq 0.1 μ F; 0402 \geq 0.47 μ F; 0603 \geq 0.68 μ F;0805 \geq 2.2 μ F; 1206 \geq 4.7 μ F; 1210 \geq 22 μ F; TT series	
	(Dissipation Factor)		10V	≦5%		≦10%	0201≥0.012μF;0402≥0.33μF(0402/ X7R≥0.22μF); TT series 0603≥0.33μF; 0805≥2.2μF;1206≥2.2μF;1210≥22μF	
		X5R: 01R5≧103, 0201≧224				≦15%	0201≧0.1µF; 0402≧1µF	
		(6.3V,10V), 0402≧475 (6.3V), 0402≧225(10V), 0603=106 (6.3V,10V),	6.3V	≦10°	%	≦15%	0201 \geq 0.1 μ F;0402 \geq 1 μ F;0603 \geq 10 μ F; 0805 \geq 4.7 μ F; 1206 \geq 47 μ F :1210 \geq 100 μ F; TT series	
		TT18X ≧475(10V) , TT15X series X6S:0201≧224 (6.3V),0402≧225				≦20%	0402≧2.2µF	
		(6.3V),	4V	≦15°	%	-	-	
			Y5V:					
			Rated vol.	D).F.≦		Exception of D.F. \leq	
			≧50V		5%	7%	0603≧0.1μF; 0805≧0.47μF; 1206≧4.7μF	
			35V		7%	-	-	
			25V		5%	7%	0402≧0.047μF;0603≧0.1μF; 0805≧0.33μF;1206≧1μF; 1210≧4.7μF	
			250		J /0	9%	0402≧0.068μF; 0603≧0.47μF; 1206≧4.7μF; 1210≧22μF	
			16V		7%	9%	0402≧0.068μF; 0603≧0.68μF	
			(C<1µF	-)	1 /0	12.5%	0402≧0.22µF	
					ıF)	9%	12.5%	0603≧2.2μF; 0805≧3.3μF; 1206≧10μF; 1210≧22μF; 1812≧47μF
			10V	12	2.5%	20%	0402≧0.47µF	
			6.3V	2	20%	-	-	





No	Item	Test Condition	Requirements			
4	Dielectric Strength	To apply voltage (≤100V) 250%. Duration: 1 to 5 sec. Charge and discharge current less than 50mA.	No evidence of damage or flash over during	ng test.		
			10GΩ or RxC≧500Ω-F whichever is smaller. Class II (X7R, X5R, X6S, Y5V)			
			Rated voltage	Insulation Resistance		
ı			100V: X7R			
			50V:0603≥1μF;0805≥1μF;1206≥4.7μF; 1210≥4.7μF			
			35V:0805≥2.2µF;1210≧10µF	j		
			25V:0402≥1µF;0603≥2.2µF;0805≥2.2µF; 1206≥10µF;1210≥10µF	10G or RxC≧100ΩF		
	Insulation Resistance		16V:0402≥0.22μF;0603≥1μF;0805≥2.2μF; 1206≥10μF;1210≥47μF	whichever is smaller.		
5		To apply rated voltage for max. 120 sec.	10V:0201≥47nF;0402≥0.47µF;0603≥0.47µF; 0805≥2.2µF; 1206≥4.7µF;1210≥47µF	1		
ı			6.3V ; 4V			
			All X6S items			
			50V: 0402≥0.1µF; 0603≥2.2µF; 0805≥10µF;1206≥10µF			
			35V: 0603≥1μF;	j		
			25V: 0201≥0.1µF; 0402≥0.22µF;	1 0 50 0 5		
			0603≥10μF;1206≥22μF	RxC≧50 Ω-F.		
			16V: 0603≥10µF			
			10V: 0201>0.1μF; 0603≥10μF; 0805≥47μF			
			6.3V: 0201≥0.1µF; 1206≥10µF			
			4V:0603≥22μF; 0805≥47μF			
		With no electrical load.				
		T.C. Operating Temp	T.C. Capacitance Change			
		NPO -55~125°C at 25°C	NPO Within ±30ppm/°C			
6	Temperature Coefficient	X7R -55~125°C at 25°C	X7R Within ±15%			
	Coefficient	X5R -55~ 85°C at 25°C	X5R Within ±15%			
		X6S -55~105°C at 25°C	X6S Within ±22%			
		Y5V -25~ 85°C at 20°C	Y5V Within +30%/-80%			
7	Adhesive Strength of Termination	Pressurizing force: 1N (0201) and 5N (≤0603) and 10N (>0603) * Test time: 10±1 sec.	No remarkable damage or removal of the termination			
8	Vibration Resistance	Vibration frequency: 10~55 Hz/min. Total amplitude: 1.5mm Test time: 6 hrs. (Two hrs each in three mutually perpendicular directions.) Measurement to be made after keeping at room temp. for 24±2 hrs.	Cap change and Q/D.F.: To meet initial spec.			





No	Item		Test Condition		Requirements		
9	Solderability		temperature: 235±5°C g time: 2±0.5 sec.		95% min. coverage of all metalized area.		
10.	Bending Test	pressu izing ro second 1 mm a mainta	iddle part of substrate shal rized by means of the present a rate of about 1 mm d until the deflection becomend then the pressure shall ined for 5±1 sec. Measure made after keeping at room 2 hrs.	ssur- per nes II be ment	No remarkable damage. Cap change: NP0: within ±5% or 0.5pF whichever is larger X7R, X5R, X6S: within ±12.5% Y5V: within ±30% (This capacitance change means the change of capacitance under specified flexure of substrate from the capacitance measured before the test.)		
11	Resistance to Soldering Heat	Solder temperature: 260±5°C Dipping time: 10±1 sec Preheating: 120 to 150°C for 1 minute before immerse the capacitor in a eutectic solder. Before initial measurement (Class II only): Perform 150+0/-10°C for 1 hr and then set for 24±2 hrs at room temp. Measurement to be made after keeping at room temp. for 24±2 hrs.			No remarkable damage. Cap change: NP0: within ±2.5% or 0.25pF whichever is larger X7R, X5R, X6S: within ±7.5% Y5V: within ±20% Q/D.F., I.R. and dielectric strength: To meet initial requirements. 25% max. leaching on each edge.		
		the ten	ct the five cycles according nperatures and time.	g to			
		Step	Temp. (°C)	(min.)	No remarkable damage.		
		1	Min. operating temp. +0/-3	30±3	Cap change:		
	Temperature	2	Room temp.	2~3	NP0: within ±2.5% or 0.25pF whichever is larger		
12	Cycle	3	Max. operating temp. +3/-0	30±3	X7R, X5R, X6S: within ±7.5% Y5V: within ±20%		
		4	Room temp.	2~3	Q/D.F., I.R. and dielectric strength: To meet initial		
			initial measurement (Clas Perform 150+0/-10°C for 1 et for 24±2 hrs at room ten rement to be made after ke n temp. for 24±2 hrs.	hr and np.	requirements.		



No	Item	Test Condition			R	Requirements
			Cap cha NP0: wi X7R, X5 TT serie **10V: 0 Y5V: ≥1 Q/D.F. N NP0: M Less tha	ange: ithin ±5% 5R, X6S es & C≥ 0603≧4. l 0V, with value: ore than	: ≥10V** 1uF,withi 7μF;040 in ±30% 30pF Q Q≥200+	F whichever is larger within ±12.5%; ≤6.3V within ±25%; in ±25% 2≥1μF;0201≥0.1μF, within ±25%; ; ≤6.3V, within +30/-40% ≥350, 10pF≤C≤30pF, Q≥275+2.5C
			Rated vol.	D.F.≦		Exception of D.F. ≦
		Test temp.: 40±2°C Humidity: 90~95% RH		-00/	≦6%	1206≧0.47μF
			≧100V	≦3%	≦7.5%	0805>0.1μF, 0603≧0.068μF
					≦6%	0201(50V); 0603≥0.047μF; 0805≥0.18μF;1206≥0.47μF
			 ≥50V	≤3 %	≦10%	1210≧4.7μF
13	Humidity (Damp Heat)	Test time: 500+24/-0hrs. Before initial measurement (Class II only): Perform 150+0/-10°C for 1 hr and			≦20%	0402≥0.1μF; 0603≥1μF; 0805≥1μF;1206≥4.7μF; 1210≥10μF TT series
	Steady State	then set for 24±2 hrs at room temp. Measurement to be made after	35V	≦5%	≦20%	0603≧1μF; 0805≥2.2μF; 1210≧10μF
					≦10%	0201≧0.01μF;0805≧1μF; 1210≧10μF
		keeping at room temp. for 24±2 hrs.			≦14%	0603≧0.33μF; 1206≧4.7μF
			25V	≦5%	≦15%	0402≧0.10μF;0603≧0.47μF;0805≧2.2 μF; 1206≧6.8μF ; 1210≧22μF; TT series
					≦20%	0402≧1µF
					≦10%	0201≧0.01μF; 0402≧0.033μF; 0805≧0.68μF;1206≧2.2μF;1210≧4.7μF
			16V	≦5%	≦15%	0201≥0.1μF; 0402≥0.47μF; 0603≥0.68μF;0805≥2.2μF; 1206≥4.7μF; 1210≥22μF; TT series
			10V	≦7.5%	≦15%	0201≧0.012µF 0402≧0.33µF; 0603≧0.33µF; 0805≧2.2µF; 1206≧2.2µF; 1210≧22µF
					≦20%	0201≧0.1μF; 0402≧1μF TT series
			6.3V	≦15%	≦30%	0201≥0.1μF;0402≥1μF;0603≥10μF; 0805≥4.7μF; 1206≥47μF :1210≥100μF; TT series
			4V	≦20%	-	-



No	Item	Test Condition	Requirements						
			Y5V:						
			Rated vol.	D.F.≦		Exception	eption of D.F. ≦		
			≧50V	7.5%	10%	0603≧0.1µF; 080	5≧0.47μF; 1206≧4.7μF		
			35V	10%	-	-			
			25V	7.5%	10%	0402≧0.047µF;0 0805≧0.33µF;12	603≧0.1μF; 06≧1μF; 1210≧4.7μF		
				7.576	15%	0402≧0.068µF; 0 1206≧4.7µF; 121			
			16V	10%	12.5%	0402≧0.068µF; 0	0603≧0.68µF		
			(C<1µF)	10 /6	20%	0402≧0.22µF			
			16V (C≧1.0µF)	12.5%	20%	0603≧2.2µF; 080 1210≧22µF; 181	05≧3.3μF; 1206≧10μF; 2≧47μF		
			10V	20%	30%	0402≧0.47µF			
			6.3V	30%	-	-			
13			*I.R.: ≥10V Class II (X			-F whichever is , Y5V)	s smaller.		
			Rated voltage Insulation Resistance						
			100V: X7R						
			50V: 0402≥ 1206≥4.7µ			F;0805≥1µF;			
			35V: 0603	≥1µF; 08	uF;1210≧10μF				
			25V:0402≥ 1206≥10µF			F;0805≥2.2μF;	1GΩ or RxC≧10 Ω-F		
			16V:0402≥ 1206≥10µF			ıF;0805≥2.2μF;	whichever is smaller.		
			10V:0201≥ μF;0805≥2		102≥0.47	7μF;0603≥0.47			
			1206≥4.7µ	F;1210≥	:47μF				
			6.3V ; 4V						
14	Humidity (Damp Heat) Load	Test temp.: 40±2°C Humidity: 90~95%RH Test time: 500+24/-0 hrs. To apply voltage: rated voltage. Before initial measurement (Class II only): To apply test voltage for 1hr at 40°C and then set for 24±2 hrs at room temp. Measurement to be made after	No remarkable damage. Cap change: NP0: $\pm 7.5\%$ or 0.75pF whichever is larger. X7R, X5R, X6S: $\geq 10V^{**}$, within $\pm 12.5\%$; $\leq 6.3V$ within $\pm 25\%$ TT series & C ≥ 1 uF, within $\pm 25\%$ **10V: $0603 \geq 4.7\mu$ F; $0402 \geq 1\mu$ F; $0201 \geq 0.1\mu$ F, within $\pm 25\%$; Y5V: $\geq 10V$, within $\pm 30\%$; $\leq 6.3V$, within $\pm 30/-40\%$ Q/D.F. value:						





lo	Item	Test Condition	Requirements					
			X7R, X5	5R, X6	SS:			
			Rated vol.	D.F.≦	É		Exception of D.F. ≦	
			1			≦6%	1206≧0.47µF	
			≥100V	≦3%		7.5%	0805>0.1μF, 0603≧0.068μF	
					É	≦6%	0201(50V); 0603≧0.047μF; 0805≧0.18μF;1206≧0.47μF	
			 ≥50V	≦3%	_ ≦	≦10%	1210≧4.7µF	
						≦20%	0402≧0.1μF; 0603≧1μF; 0805≧1μF;1206≧4.7μF; 1210≧10μF TT series	
			35V	≦5%	_ ≦	≦20%	0603≧1μF; 0805≥2.2μF; 1210≧10μF	
					≦	≦10%	0201≧0.01μF;0805≧1μF; 1210≧10μF	
					≦	≦14%	0603≧0.33μF; 1206≧4.7μF	
			25V	≦5%		≦15%	0402≧0.10μF;0603≧0.47μF;0805≧2.2 μF; 1206≧6.8μF ; 1210≧22μF; TT series	
					≦	≦20%	0402≧1µF	
					≦	≦10%	0201≥0.01μF; 0402≥0.033μF; 0805≥0.68μF;1206≥2.2μF;1210≥4.7μF	
	Humidity	Heat)	16V	≦5%		≦15%	0201 \ge 0.1 μ F; 0402 \ge 0.47 μ F; 0603 \ge 0.68 μ F; 0805 \ge 2.2 μ F; 1206 \ge 4.7 μ F; 1210 \ge 22 μ F; TT series	
4	(Damp Heat) Load		10V	≦7.5%		≦15%	0201≧0.012μF 0402≥0.33μF; (0402/ X7R≥0.22μF); 0603≥0.33μF; 0805≥2.2μF; 1206≥2.2μF; 1210≥22μF	
					≦	≦20%	0201≧0.1μF; 0402≧1μF; TT series	
			6.3V	6.3V ≦15%		≦30%	0201 \ge 0.1 μ F;0402 \ge 1 μ F;0603 \ge 10 μ F; 0805 \ge 4.7 μ F; 1206 \ge 47 μ F :1210 \ge 100 μ F; TT series	
			4V	≦20%	6	- 1	-	
			Y5V:					
			Rated vol.	D.	.F.≦		Exception of D.F. ≦	
			≧50V	7.	.5%	10%	0603≧0.1μF; 0805≧0.47μF; 1206≧4.7μF	
			35V	10	0%	-	-	
			25V	7	.5%	10%	0402≧0.047μF;0603≧0.1μF; 0805≧0.33μF;1206≧1μF; 1210≧4.7μF	
			250		.5 /0	15%	0402≧0.068μF; 0603≧0.47μF; 1206≧4.7μF; 1210≧22μF	
			16V	11	0%	12.5%	0402≧0.068μF; 0603≧0.68μF	
			(C<1µF) "	J /0	20%	0402≧0.22μF	
			16V (C≧1.0µ	F) 12	2.5%	20%	0603≧2.2μF; 0805≧3.3μF; 1206≧10μF; 1210≧22μF; 1812≧47μF	
			10V	20	0%	30%	0402≧0.47μF	
- [6.3V	30	0%	-	-	





No	Item	Test Condition	Requirements					
			*I.R.: ≥10V, 500MΩ or 25 Ω-F whichever Class II (X7R, X5R, X6S, Y5V)	is smaller.				
			Rated voltage	Insulation Resistance				
			100V: X7R					
	Humidity		50V: 0402≥0.1µF;0603≥1µF;0805≥1µF; 1206≥4.7µF;1210≥4.7µF					
14	(Damp Heat)		35V: 0603≥1µF; 0805≥2.2µF;1210≧10µF					
	Load		25V:0402≥1µF;0603≥2.2µF;0805≥2.2µF; 1206≥10µF;1210≥10µF	500GΩ or RxC≧5 Ω-F whichever is				
			16V:0402≥0.22µF;0603≥1µF;0805≥2.2µF; 1206≥10µF;1210≥47µF	smaller.				
			10V:0201≥47nF;0402≥0.47μF;0603≥0.47 μF;0805≥2.2μF; 1206≥4.7μF;1210≥47μF					
			6.3V; 4V; TT series; All X6S items					
15.	High Temperature Load (Endurance)	*Test temp.: NP0, X7R/X7E: 125±3°C X6S: 105±3°C X5R, Y5V: 85±3°C *Test time: 1000+24/-0 hrs. *To apply voltage: 1) ≦% of rated voltage. 2) 10V≦Ur<500V: 200% of rated voltage. 3) 500V: 150% of rated voltage. 4) Ur≧630V: 120% of rated voltage. *Test temp.: No remarkable damage. Cap change: NP0: ±3.0% or ±0.3pF whichever is larger X7R, X5R, X6S: ≥10V**, within ±12.5%; ≦6.3V within ±12.5%; ≤6.3V within ±25% ***10V: 0603≥4.7µF;0402≥1µF;0201≥0.1µF, within ±2 Y5V: ≥10V, within ±30%; ≤6.3V, within +30/-40% Q/D.F. value: NP0: More than 30pF, Q≥350 10pF≤C<30pF, Q≥275+2.5C Less than 10pF, Q≥200+10C						





No	Item		Test	Condition	1			F	Requirements
						X7R, X	5R, X6	3:	
		5) 100°	% of rated	voltage fo	r below	Rated vol.	D.F.≦		Exception of D.F. ≦
		rang		3 - 3 - 3		>100\/	=20/	≦6%	1206≧0.47µF
				Rated	Capaci-	≥100V	≦3%	≦7.5%	0805>0.1μF, 0603≧0.068μF
		Size	Dielectric	voltage	tance range			≦6%	0201(50V); 0603≧0.047μF; 0805≧0.18μF;1206≧0.47μF
		0201	X5R/X7R/ X6S	6.3V,10V	C≧0.1µF	≥50V	≦3%	≦10%	1210≧4.7µF
		0402	X5R/X7R/ X6S	6.3V,10V	C≧1.0μF			≦20%	0402≧0.1μF; 0603≧1μF; 0805≧1μF;1206≧4.7μF; 1210≧10μF TT series
				4V	C≧22µF	35V	≦5%	≦20%	0603≧1μF; 0805≥2.2μF; 1210≧10μF
		0603	X5R/X7R/ X6S	6.3V,10V	C≧4.7µF			≦10%	0201≧0.01μF;0805≧1μF; 1210≧10μF
				35V	C≧1.0µF			≦14%	0603≧0.33μF; 1206≧4.7μF
		0805	X5R/X7R/ X6S	4V 6.3V	C≧47µF	25V	≦5%	≦15%	0402≧0.10μF;0603≧0.47μF;0805≧2.2 μF; 1206≧6.8μF ; 1210≧22μF; TT series
		-	ļ	-	C≧22µF			≦20%	0402≧1µF
		1206	X5R/X7R/ NP0	6.3V 3,000V	C≧47μF C≧1.5pF			≦10%	0201≧0.01μF; 0402≧0.033μF; 0805≧0.68μF;1206≧2.2μF;1210≧4.7μF
	High Temperature Load (Endurance)	TT18	Y5V	6.3V,10	C≧2.2µF	16V	≦5%	≦15%	0201≥0.1μF; 0402≥0.47μF; 0603≥0.68μF;0805≥2.2μF; 1206≥4.7μF;
		TT21	Y5V Y5V	6.3V 6.3V	C≧10µF C≧22uF				1210≧22µF; TT series
15		` ')% of rated			10V	≦7.5%	≦15%	0201≥0.012µF 0402≥0.33µF; 0603≥0.33µF; 0805≥2.2µF; 1206≥2.2µF; 1210≥22µF;
	(Endurance)	ran	ge.					≦20%	0201≧0.1μF; 0402≧1μF
		Size	Dielectric	Rated voltage	Capaci- tance range	6.3V	6.3V ≦15%		0201≥0.1μF;0402≥1μF;0603≥10μF; 0805≥4.7μF; 1206≥47μF :1210≥100μF; TT series
		0201	X5R/X7R/	16V	C≧0.1µF	4V	≦20%	 	-
		\parallel	X6S	501/			=2070	<u> </u>	1
		0402	X5R/X7R/ X6S	50V 10V~25V	C≧0.1μF C≧0.22μF	Y5V:	D.F	. <	Exception of D.F. ≦
			Y5V	16V	C≧0.47µF	vol.			·
			X5R/X7R/	10V,50V	C≧1.0µF	≧50V 35V	7.5		0603≥0.1μF; 0805≥0.47μF; 1206≥4.7μF
		0603	X6S			350	10	% - 	- 0402≧0.047μF;0603≧0.1μF;
			Y5V X5R/X7R/	16V	C≧2.2μF	25V	7.5	% 10%	0805≧0.33μF;1206≧1μF; 1210≧4.7μF
			X6S	10~50V	C≧4.7µF			15%	0402≥0.068μF; 0603≥0.47μF; 1206≥4.7μF; 1210≥22μF
		0805	X7R	50V	C≧2.2µF	16V	10	12.5%	0402≧0.068µF; 0603≧0.68µF
				100V	C≧0.47µF	(C<1µF	10	% 20%	0402≧0.22μF
		2220	Y5V X7R	16V 100V	C≧4.7μF C≧6.8μF	16V (C≧1.0µ	ıF) 12.	5% 20%	0603≧2.2μF; 0805≧3.3μF; 1206≧10μF; 1210≧22μF; 1812≧47μF
						10V	20	% 30%	0402≧0.47μF
					6.3V	30	% -	-	

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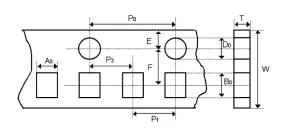
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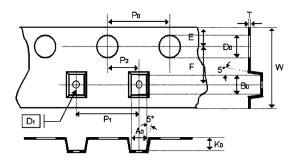
No	Item	Test Condition	Requirements				
		*Before initial measurement (Class II only): To apply test voltage for 1hr at test temp. and	*I.R.: ≥10V, 1GΩ or 50 Ω-F whichever is smaller. Class II (X7R, X5R, X6S, Y5V)				
		then set for 24±2 hrs at room temp.	Rated voltage	Insulation Resistance			
		*Measurement to be made after keeping at room temp. for 24±2 hrs	100V: X7R				
	High Temperature		50V: 0402≥0.1μF;0603≥1μF;0805≥1μF; 1206≥4.7μF;1210≥4.7μF				
15	Load		35V: 0603≥1µF; 0805≥2.2µF;1210≧10µF				
	(Endurance		25V:0402≥1µF;0603≥2.2µF;0805≥2.2µF; 1206≥10µF;1210≥10µF	1GΩ or RxC≧10 Ω-F whichever is			
			16V:0402≥0.22µF;0603≥1µF;0805≥2.2µF; 1206≥10µF;1210≥47µF	smaller.			
			10V:0201≥47nF;0402≥0.47μF;0603≥0.47 μF;0805≥2.2μF;				
		Temperature at Product (°C)	6.3V; 4V; TT series; All X6S items				

Appendixes

Tape & Reel Dimensions



The dimension of paper tape



The dimension of plastic tape

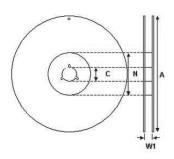
Size	0201	04	02	0603		0805			1206			1210	,		1812	
Thick- ness	L	N	E	S, X	Α	В	C, D, I	В	C, J, D	G,P	C, D	G, K	М	D, K	М	U
A ₀	0.38±0.05	0.62±0.05	0.7±0.1	1.02±0.05	1.5±0.1	1.5±0.1	<1.57	2±0.1	<1.85	<1.95	<2.97	<2.97	<2.97	<3.81	<3.81	<3.9
В0	0.68±0.05	1.12±0.05	1.2±0.1	1.8±0.05	2.3±0.1	2.3±0.1	<2.40	3.5±0.1	<3.46	<3.67	<3.73	<3.73	<3.73	<5.3	<5.3	<5.3
Т	0.42±0.05	0.6±0.05	0.7±0.1	0.95±0.05	0.75±0.05	0.95±0.05	0.23±0.05	0.95±0.05	0.23±0.05	0.23±0.05	0.23±0.05	0.23±0.05	0.23±0.05	0.25±0.05	0.25±0.05	0.25±0.05
К0	-	-	-	-	-	-	<2.5	-	<2.5	<2.5	<2.5	<2.5	<3	<2.5	<3	<3.5
W	8±0.1	8±0.1	8±0.1	8±0.1	8±0.1	8±0.1	8±0.1	8±0.1	8±0.1	8±0.1	8±0.1	8±0.1	8±0.1	12±0.2	12±0.2	12±0.2
P ₀	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1
10xP ₀	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.1	40±0.2
P1	2±0.05	2±0.05	2±0.05	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.1	4±0.10	4±0.1	8±0.1	8±0.1	8±0.1
P ₂	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05	2±0.05
D ₀	1.55±0.05	1.55±0.05	1.55±0.05	1.55±0.05	1.55±0.05	1.55±0.05	1.5±0.05	1.5±0.05	1.5±0.05	1.5±0.05	1.5±0.05	1.5±0.05	1.5±0.05	1.5±0.05	1.5±0.05	1.5±0.1
D ₁	-	-	-	-	-	-	1±0.1	-	1±0.1	1±0.1	1±0.1	1±0.1	1±0.1	1.5±0.1	1.5±0.1	1.5±0.1
E	1.75±0.05	1.75±0.05	1.75±0.05	1.75±0.05	1.75±0.05	1.75±0.05	1.75±0.1	1.75±0.1	1.75±0.1	1.75±0.1	1.75±0.1	1.75±0.1	1.75±0.1	1.75±0.1	1.75±0.1	1.75±0.1
F	3.50±0.05	3.5±0.05	3.5±0.05	3.5±0.05	3.5±0.05	3.5±0.05	3.5±0.05	3.5±0.05	3.5±0.05	3.5±0.05	3.5±0.05	3.5±0.05	3.5±0.05	5.5±0.05	5.5±0.05	5.5±0.05

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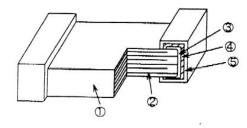




Size	0201, 0402	0201, 0402, 0603, 0805, 1206, 1210							
Reel size	7"	7" 10"		7"					
С	13 +0.5/-0.2	13 +0.5/-0.2	13 +0.5/-0.2	13 +0.5/-0.2					
W1	8.4 +1.5/-0	8.4+1.5/-0	8.4 +1.5/-0	12.4+2.0/-0					
Α	178 ±0.1	250 ±1	330 ±1	178 ±0.1					
N	60 +1/-0	100 ±1	100 ±1	60 +1/-0					

The dimension of reel

Constructions:



No.	Na	me	NPO, X7R, X5R, X6S, Y5V
1	Ceramic	material	BaTiO₃ based
2	Inner el	ectrode	Ni
3		Inner layer	Cu
4	Termination Middle layer		Ni
5		Outer layer	Sn

Storage and handling conditions

- (1) To store products at 5°C to 40°C ambient temperature and 20 to 70%. related humidity conditions.
- (2) The product is recommended to be used within one year after shipment. Check solderability in case of shelf life extension is needed.

Cautions:

- a. The corrosive gas reacts on the terminal electrodes of capacitors, and results in the poor solderability. Do not store the capacitors in the ambience of corrosive gas (e.g., hydrogen sulfide, sulfur dioxide, chlorine, ammonia gas etc.)
- b. In corrosive atmosphere, solderability might be degraded, and silver migration might occur to cause low reliability.
- c. Due to the dewing by rapid humidity change, or the photochemical change of the terminal electrode by direct sunlight, the solderability and electrical performance may deteriorate. Do not store capacitors under direct sunlight or dewing condition. To store products on the shelf and avoid exposure to moisture.

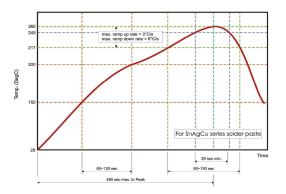




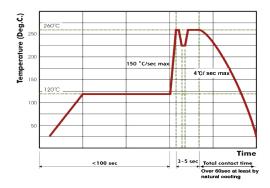


Recommended Soldering Conditions:

The lead-free termination MLCCs are not only to be used on SMT against lead-free solder paste, but also suitable against lead-containing solder paste. If the optimized solder joint is requested, increasing soldering time, temperature and concentration of N₂ within oven are recommended.



Recommended reflow soldering profile for SMT process with SnAgCu series solder paste.



Recommended wave soldering profile for SMT process with SnAgCu series solder.

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